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PATENT
Attorney Docket No.: 018865-003200US
Client Ref. No.: 17732-9345

Assistant Commissioner for Patents
Washington, D.C. 20231

On October 10, 2002

TOWNSEND and TOWNSEND and CREW LLP

By: Digi Hoover

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Bruce D. Marchant et al.

Application No.: 09/405,210

Filed: September 24, 1999

For: METHOD OF MANUFACTURING
TRENCH FIELD EFFECT
TRANSISTORS WITH TRENCHED
HEAVY BODY

Examiner: VU, David

Art Unit: 2818

PRELIMINARY AMENDMENT

RECEIVED
OCT 16 2002
TECHNOLOGY CENTER 2800

Assistant Commissioner for Patents
Washington, D.C. 20231

Sir:

Prior to further examination of the above-referenced application, please enter the following amendments and remarks.

IN THE CLAIMS:

Please amend claims 1 and 13 as follows:

- 1 1. (Twice Amended) A method of manufacturing a trench field effect
2 transistor on a substrate having a first conductivity type, the method comprising the steps
3 of:
4 forming a first trench extending into the substrate;